

SFH 4775S A01

SYNIOS® P2720

IR SYNIOS P2720 (940 nm) - 120°



Applications

- Driver Monitoring / Seat Occupancy Detection
- Electronic Equipment
- Eye Tracking

Features:

- Package: clear silicone
- Corrosion Robustness Class: 3B
- Qualifications: The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- IR lightsource with high efficiency
- Double stack emitter
- Low thermal resistance (Max. 9 K/W)
- Centroid wavelength 940 nm

Ordering Information

Type	Total radiant flux ¹⁾²⁾ $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ Φ_e	Total radiant flux ¹⁾ typ. $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ Φ_e	Ordering Code
SFH 4775S A01	900 ... 1400 mW	1,100 mW	Q65112A4690

Maximum Ratings

Parameter	Symbol		Values
Operating temperature	T_{op}	min. max.	-40 °C 125 °C
Storage temperature	T_{stg}	min. max.	-40 °C 125 °C
Junction temperature	T_j	max.	145 °C
Forward current	I_F	max.	1500 mA
Surge current $t_p \leq 300 \mu s$; $D = 0.005$	I_{FSM}	max.	5 A
Reverse current ³⁾	I_R	max.	200 mA
Power consumption	P_{tot}	max.	5.8 W
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}	max.	2 kV

For the forward current and power consumption please see "maximum permissible forward current" diagram

Characteristics

$I_F = 1000 \text{ mA}$; $t_p = 10 \text{ ms}$

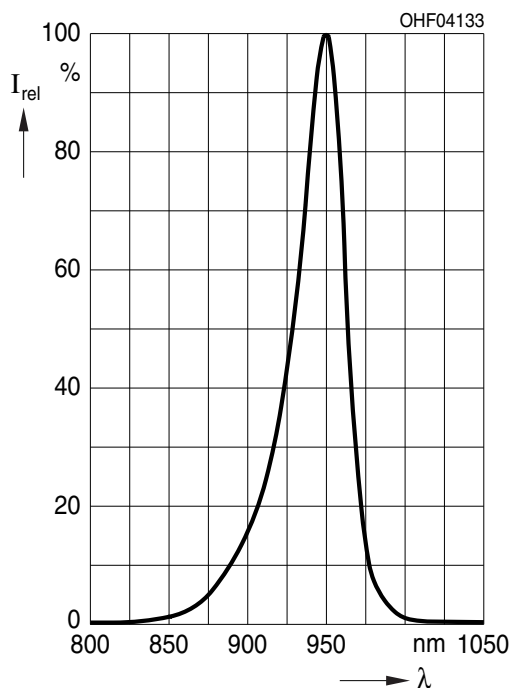
Parameter	Symbol		Values
Peak wavelength	λ_{peak}	typ.	950 nm
Centroid wavelength	$\lambda_{\text{centroid}}$	typ.	940 nm
Spectral bandwidth at 50% $I_{\text{rel,max}}$ (FWHM)	$\Delta\lambda$	typ.	37 nm
Half angle	φ	typ.	60 °
Dimensions of active chip area	L x W	typ.	1 x 1 mm x mm
Rise time (10% / 90%) $I_F = 5 \text{ A}$; $R_L = 50 \Omega$	t_r	typ.	10 ns
Fall time (10% / 90%) $I_F = 5 \text{ A}$; $R_L = 50 \Omega$	t_f	typ.	15 ns
Forward voltage ⁴⁾	V_F	min. typ. max.	2.5 V 2.65 V 3.1 V
Forward voltage ⁴⁾ $I_F = 1.5 \text{ A}$; $t_p = 100 \mu\text{s}$	V_F	min. typ. max.	2.6 V 2.75 V 3.35 V
Forward voltage ⁴⁾ $I_F = 5 \text{ A}$; $t_p = 100 \mu\text{s}$	V_F	min. typ. max.	2.9 V 3.2 V 4.2 V
Reverse voltage ³⁾ $I_R = 20 \text{ mA}$	V_R	max.	1.2 V
Reverse voltage (ESD device) ³⁾	$V_{R\text{ESD}}$	min.	5 V
Radiant intensity ⁵⁾ $I_F = 0 \text{ mA}$; $t_p = 0 \text{ ms}$	I_e	typ.	350 mW/sr
Radiant intensity ⁵⁾ $I_F = 1.5 \text{ A}$; $t_p = 100 \mu\text{s}$	I_e	typ.	530 mW/sr
Total radiant flux ¹⁾ $I_F = 1.5 \text{ A}$; $t_p = 100 \mu\text{s}$	Φ_e	typ.	1650 mW
Temperature coefficient of voltage	TC_V	typ.	-2 mV / K
Temperature coefficient of wavelength	TC_λ	typ.	0.3 nm / K
Thermal resistance junction solder point real ⁶⁾	$R_{\text{thJS real}}$	typ. max.	6.0 K / W 9.0 K / W

Brightness Groups

Group	Total radiant flux ¹⁾²⁾ $I_F = 1 \text{ A}; t_p = 10 \text{ ms}$ min. Φ_e	Total radiant flux ¹⁾²⁾ $I_F = 1 \text{ A}; t_p = 10 \text{ ms}$ max. Φ_e
EB	900 mW	1120 mW
FA	1120 mW	1400 mW

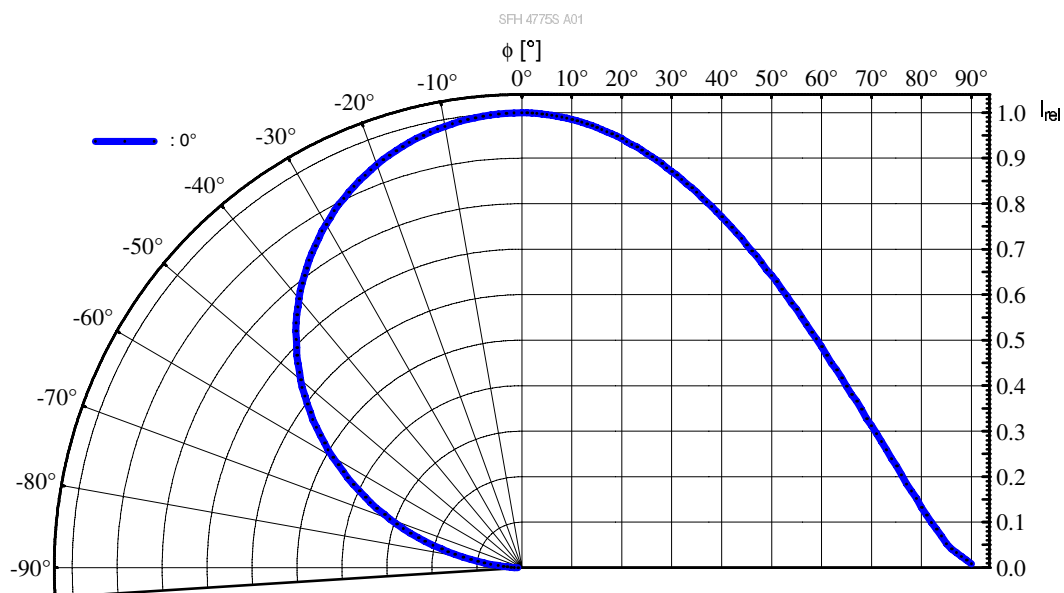
Relative Spectral Emission ^{7), 8)}

$I_{e,rel} = f(\lambda); I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$



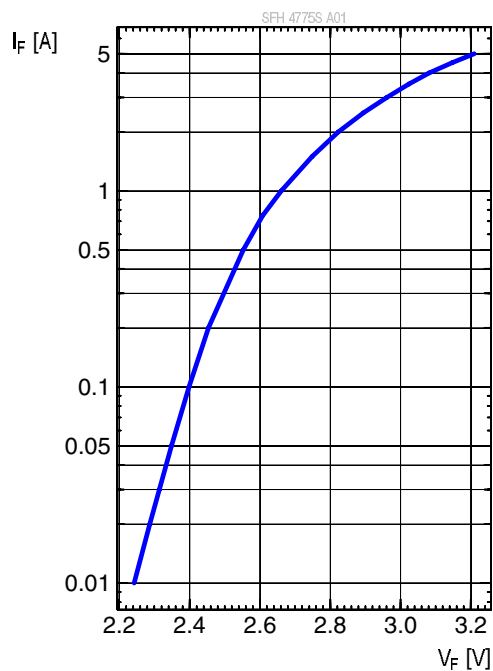
Radiation Characteristics 7), 8)

$$I_{e,rel} = f(\varphi)$$



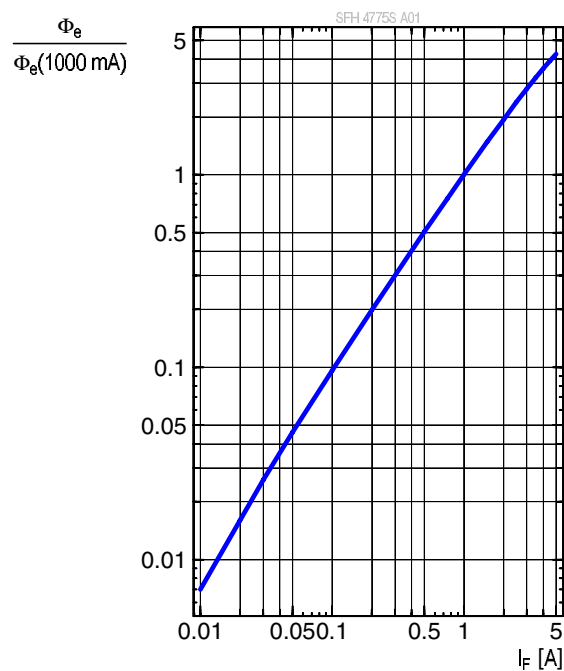
Forward current 7), 8)

$$I_F = f(V_F); \text{ single pulse; } t_p = 100 \mu s$$



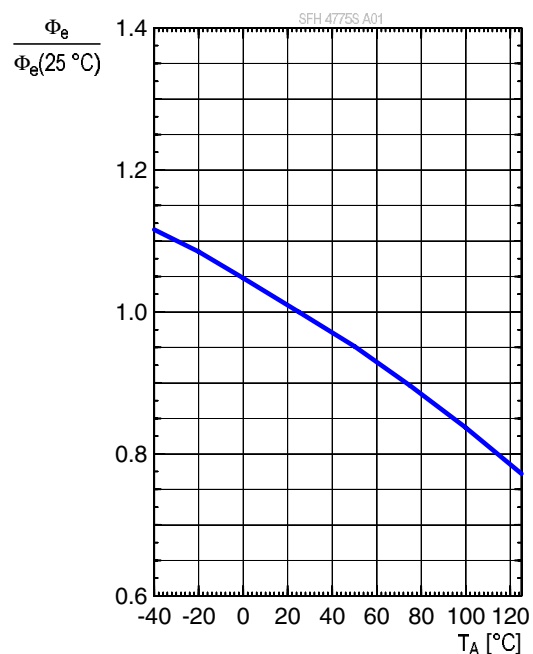
Relative Total Radiant Flux 7), 8)

$$\Phi_e / \Phi_e(1000 \text{ mA}) = f(I_F); t_p = 100 \mu s$$



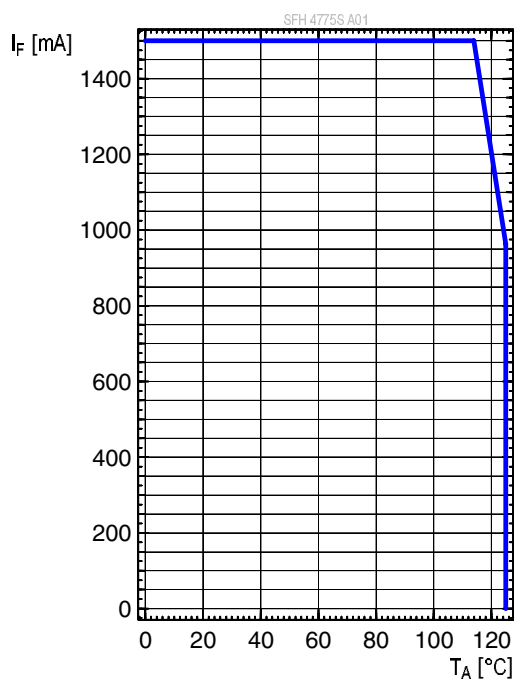
Relative Total Radiant Flux ⁷⁾

$$\Phi_e = f(T_A);$$



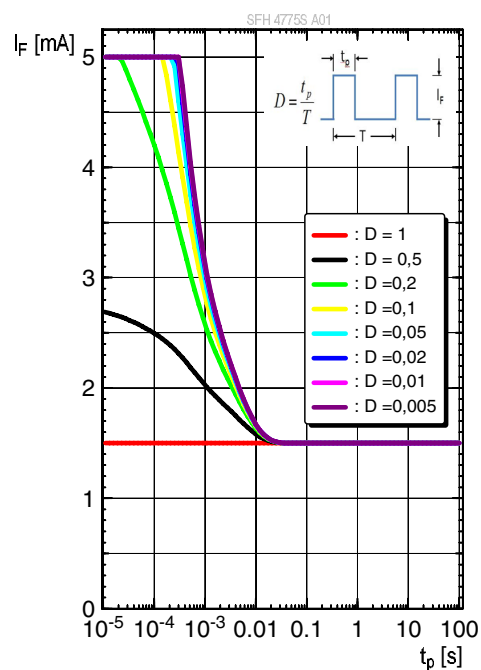
Max. Permissible Forward Current

$$I_{F,\text{max}} = f(T_A); R_{\text{thjs}} = 9 \text{ K/W}$$

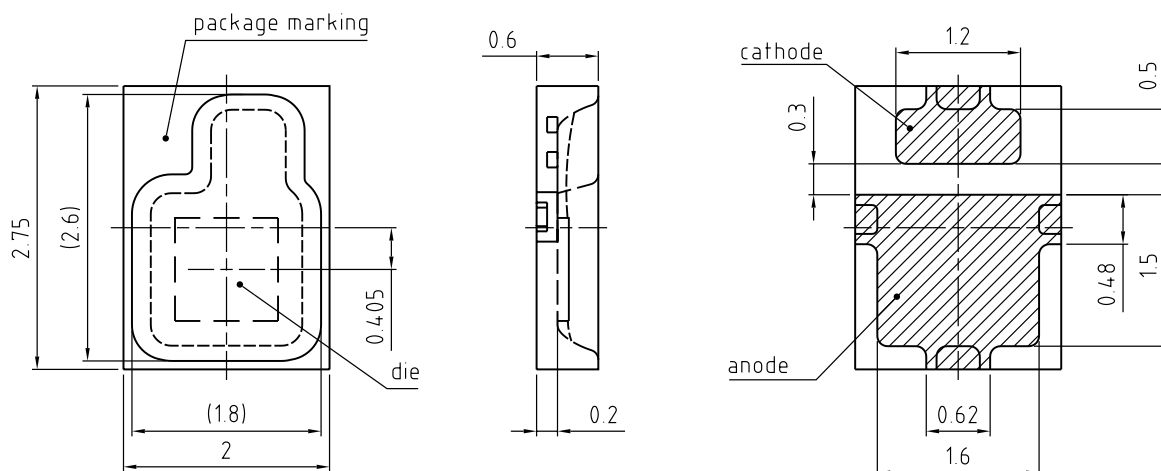


Permissible Pulse Handling Capability

$$I_F = f(t_p); T_S = 85^\circ\text{C}$$



Dimensional Drawing ⁹⁾



General tolerance ± 0.1

Lead finish Au 

C67062-A0183-A1-02

Further Information:

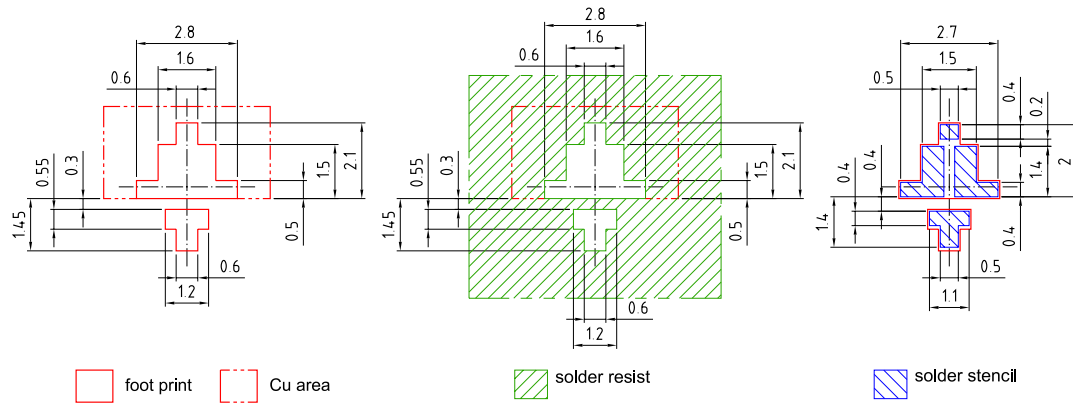
Approximate Weight: 12.0 mg

Package marking: Cathode

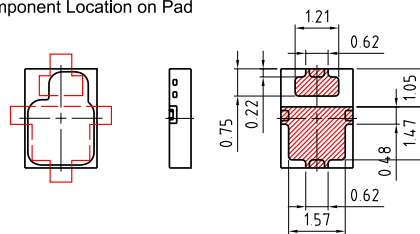
Corrosion test: Class: 3B
Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC 60068-2-43)

ESD advice: The device is protected by ESD device which is connected in parallel to the Chip.

Recommended Solder Pad ⁹⁾



Component Location on Pad



E062.3010.181 -02

Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

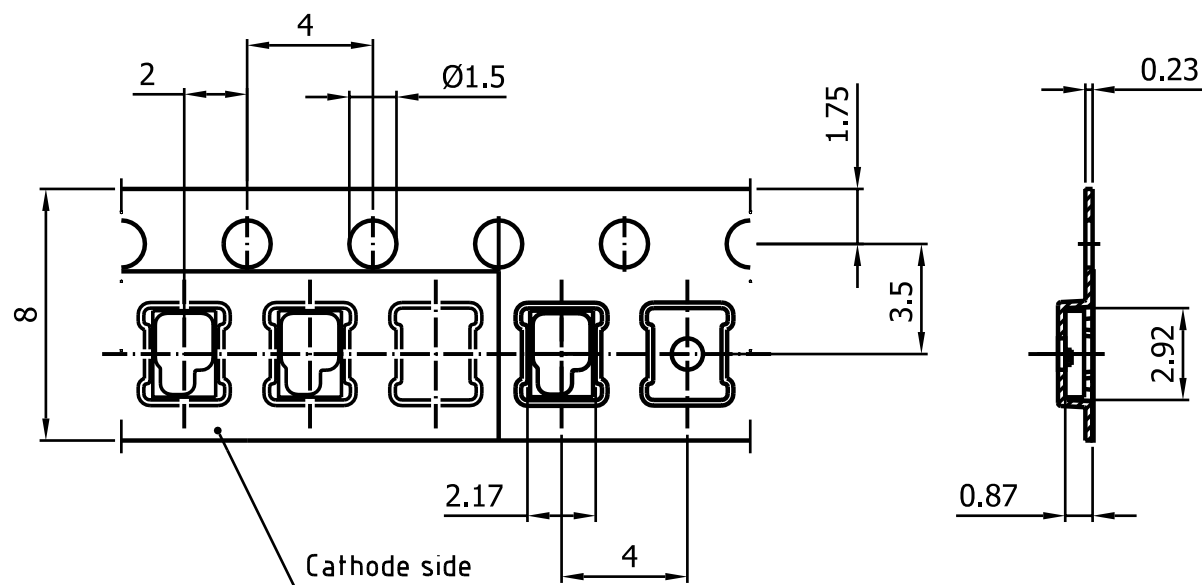


Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat ^{*)} 25 °C to 150 °C			2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t_s	60	100	120	s
Ramp-up rate to peak ^{*)} T_{Smax} to T_p			2	3	K/s
Liquidus temperature	T_L		217		$^{\circ}\text{C}$
Time above liquidus temperature	t_L		80	100	s
Peak temperature	T_p		245	260	$^{\circ}\text{C}$
Time within 5 °C of the specified peak temperature $T_p - 5 \text{ K}$	t_p	10	20	30	s
Ramp-down rate* T_p to 100 °C			3	6	K/s
Time 25 °C to T_p				480	s

All temperatures refer to the center of the package, measured on the top of the component

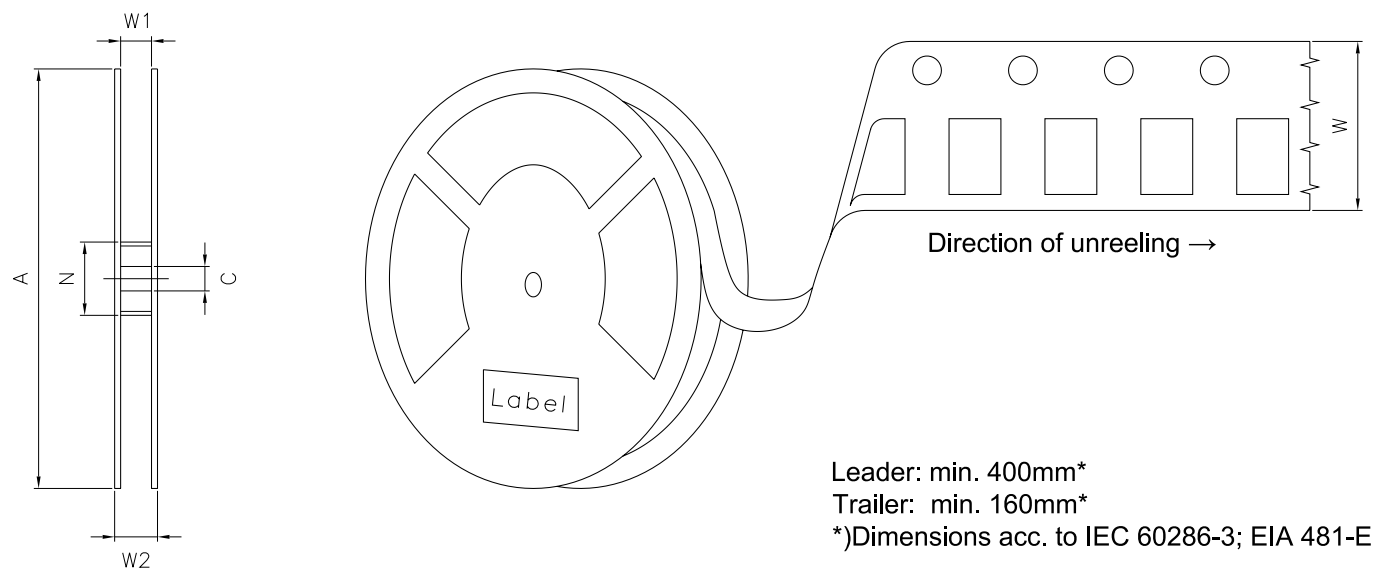
* slope calculation DT/Dt : Dt max. 5 s; fulfillment for the whole T-range

Taping ⁹⁾



C67062-A0116-B14-04

Tape and Reel ¹⁰⁾



Reel Dimensions

A	W	N _{min}	W ₁	W _{2 max}	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	2000

Barcode-Product-Label (BPL)

OSRAM Opto Semiconductors

LX XXXX BIN1: XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890

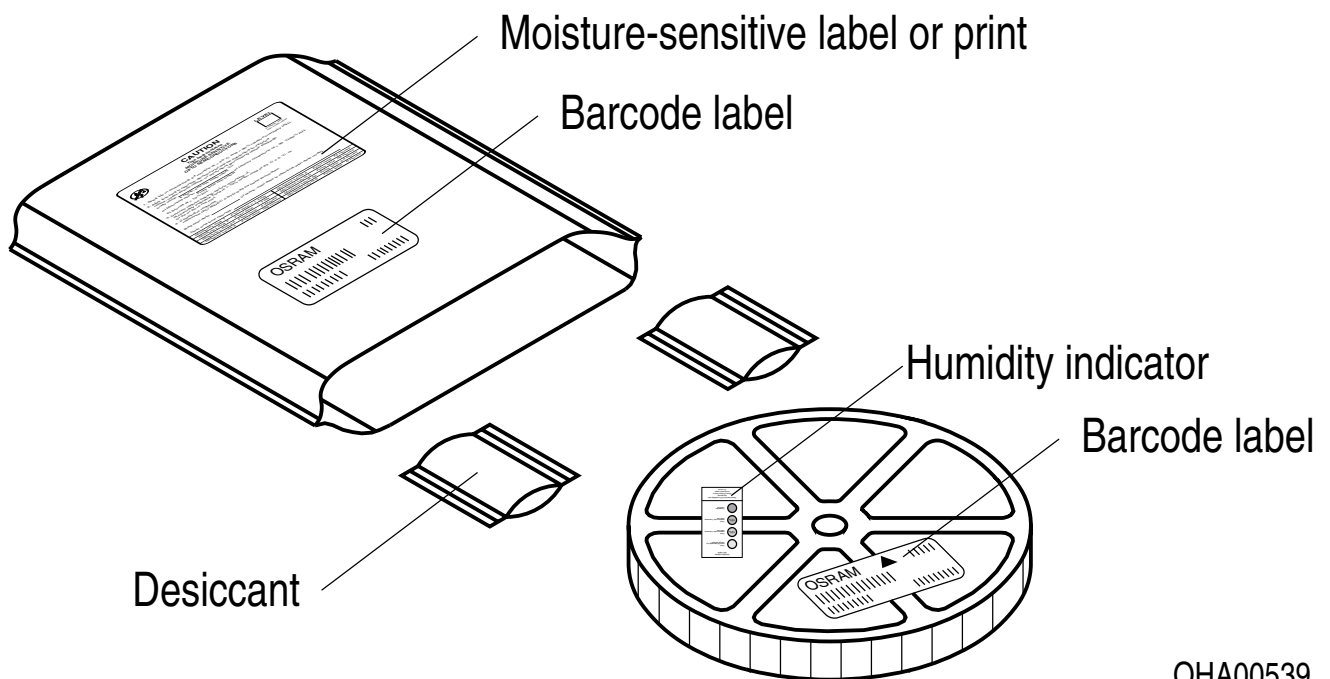
(1T) LOT NO: 1234567890 (9D) D/C: 1234

ML Temp ST
X XXX °C X

Pack: RXX
DEMY XXX
X_X123_1234.1234 X

(X) PROD NO: 123456789 (Q) QTY: 9999 (G) GROUP: XX-XX-X-X

OHA04563

Dry Packing Process and Materials ⁹⁾

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

Glossary

- 1) **Total radiant flux:** Measured with integrating sphere.
- 2) **Brightness:** The brightness values are measured with a tolerance of $\pm 11\%$.
- 3) **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 4) **Forward Voltage:** The forward voltages are measured with a tolerance of ± 0.1 V.
- 5) **Radiant intensity:** Measured at a solid angle of $\Omega = 0.01$ sr
- 6) **Thermal resistance:** junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- 7) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 8) **Testing temperature:** $T_A = 25^\circ\text{C}$ (unless otherwise specified)
- 9) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.
- 10) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

Revision History

Version	Date	Change
1.0	2019-09-18	Initial Version
1.1	2020-08-26	Schematic Transportation Box Dimensions of Transportation Box

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